

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3402 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

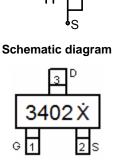
V_{DS} = 30V,I_D = 3A

 $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})} < 75 \mathrm{m}\Omega \textcircled{0} \mathsf{V}_{\mathsf{GS}} \texttt{=} 2.5 \mathsf{V}$

- $R_{DS(ON)}$ < 65m Ω @ V_{GS}=4.5V
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- Battery protection
- Load switch
- Power management



Marking and pin assignment



Package Marking and Ordering Information

U	0	<u> </u>			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3402 X	NCE3402	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	3	A
Drain Current-Pulsed (Note 1)	I _{DM}	20	A
Maximum Power Dissipation	PD	0.9	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	°C

Thermal Characteristic

	Thermal Resistance, Junction-to-Ambient (Note 2) ReJA	138	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V Ι _D =250μΑ	30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	-	1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1	1.5	3.0	V
Drain-Source On-State Resistance	P	V _{GS} =10V, I _D =3A	-	50	65	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =3 A	-	65	75	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =3A	14	-	-	S
Dynamic Characteristics (Note4)			•			•
Input Capacitance	Clss	- V _{DS} =10V,V _{GS} =0V, F=1.0MHz	-	235	-	PF
Output Capacitance	Coss		-	35	-	PF
Reverse Transfer Capacitance	Crss	F=1.0WHZ	-	18	-	PF
Switching Characteristics (Note 4)	·					•
Turn-on Delay Time	t _{d(on)}		-	3.5	-	nS
Turn-on Rise Time	tr	V _{DD} =15V,I _D =1A	-	1.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =6 Ω	-	17.5	-	nS
Turn-Off Fall Time	t _f	-	-	2.5	-	nS
Total Gate Charge	Qg		-	10	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =3A,V _{GS} =10V	-	0.95	-	nC
Gate-Drain Charge	Q _{gd}		-	1.6	-	nC
Drain-Source Diode Characteristics	L					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =3A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	3	А

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production





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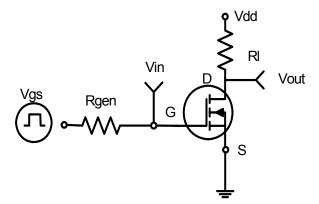
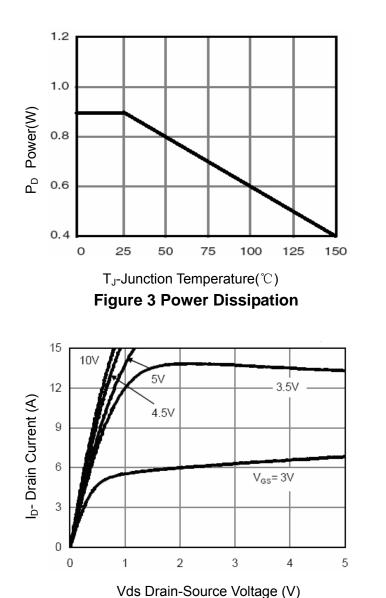


Figure 1:Switching Test Circuit



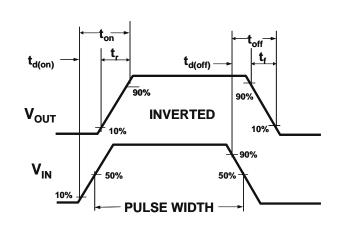
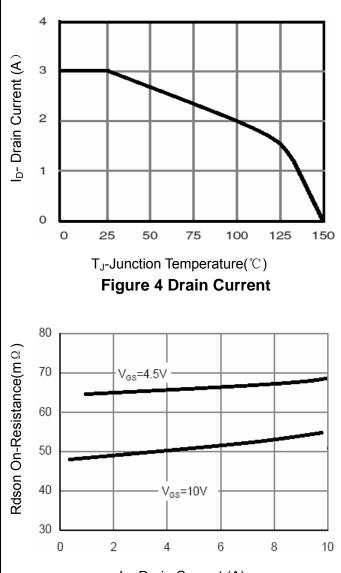


Figure 2:Switching Waveforms



I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance

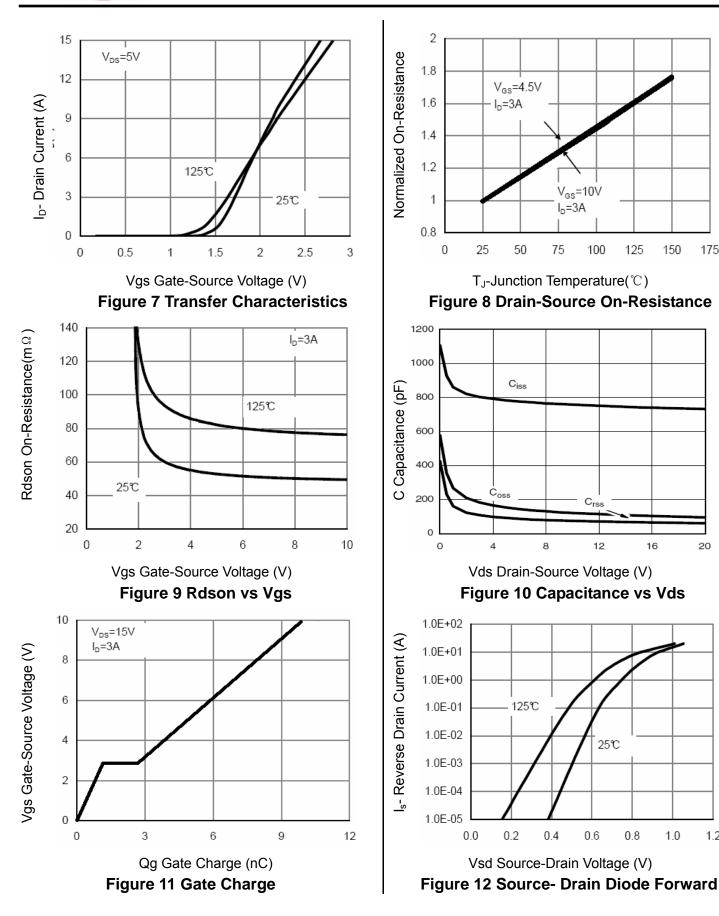
Figure 5 Output Characteristics



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175

20



1.2

100.0





Pb Free Product

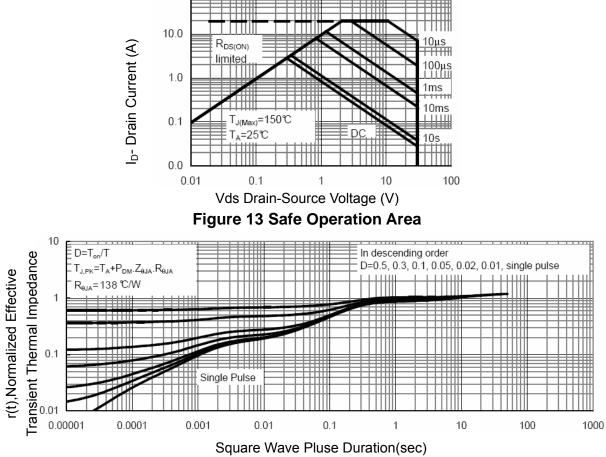
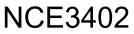
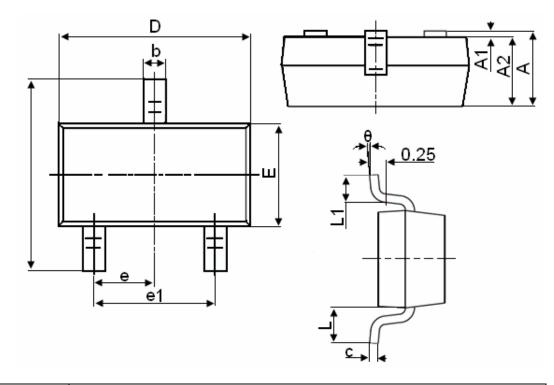


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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